

Product data sheet

1. General description

AC Thyristor power switch in a SOT54 (TO-92) plastic package with self-protective capabilities against low and high energy transients.

2. Features and benefits

- Exclusive negative gate triggering
- Full cycle AC conduction
- · Remote gate separates the gate driver from the effects of the load current
- · Safe clamping of low energy over-voltage transients
- High voltage capability
- · Self-protective turn-on during high energy voltage transients
- Very high noise immunity

3. Applications

- Fan motor circuits
- Pump motor circuits
- · Lower-power highly inductive, resistive and safety loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{lead} ≤ 75 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	0.8	A
Static chara	cteristics					
I _{GT}	gate trigger current	V_D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; Fig. 8	1	-	10	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	1	-	10	mA

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5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	СМ	common		LD			
2	G	gate					
3	LD	load	0000 0000 00000 000000 0000000 00000000	G —o ∏ <u>-∕</u> CM 001aaj924			

6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
ACT108-800E	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54		

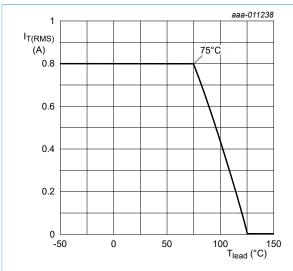
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7. Limiting values

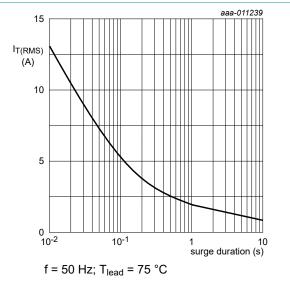
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{lead} ≤ 75 °C; <u>Fig. 1; Fig. 2;</u> <u>Fig. 3</u>	-	0.8	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	13	A
		full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms	-	14.3	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	0.84	A²s
dl _T /dt	rate of rise of on-state current	I _G = 20 mA	-	100	A/µs
I _{GM}	peak gate current	t = 20 µs	-	1	А
V _{GM}	peak gate voltage	positive applied gate voltage	-	15	V
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
V _{PP}	peak pulse voltage	T_j = 25 °C; non-repetitive, off-state; ten pulses on each voltage polarity; 20s or more between successive pulses; Fig. 6	-	2.5	kV

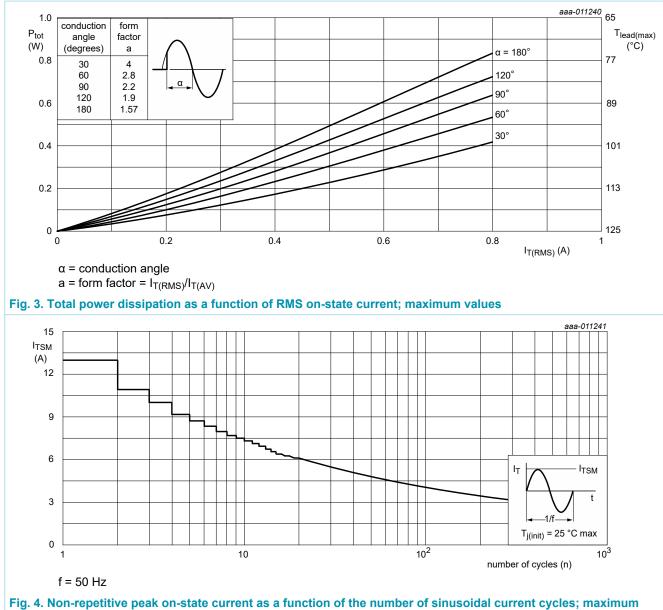








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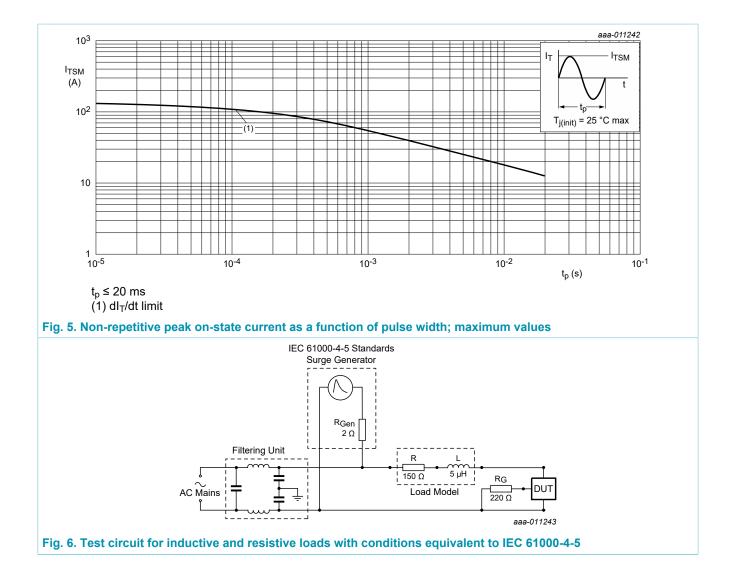


values

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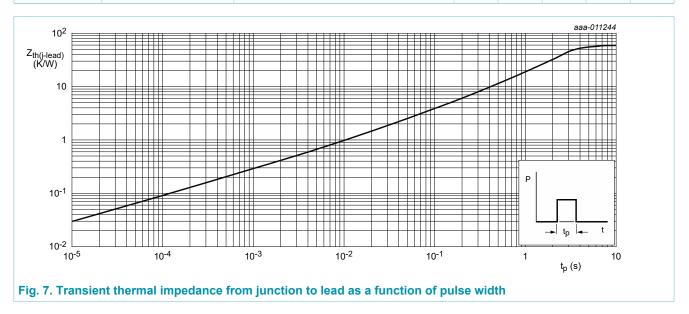
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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-lead)}	thermal resistance from junction to lead	full cycle with heatsink compound; Fig. 7	-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	full cycle; printed-circuit board mounted; lead length 4 mm	-	150	-	K/W



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9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	1	-	10	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	1	-	10	mA
IL	latching current	V _D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	25	mA
		V _D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	20	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	20	mA
V _T	on-state voltage	I _T = 1.1 A; T _j = 25 °C; <u>Fig. 11</u>	-	-	1.3	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 100 mA; T _j = 25 °C; <u>Fig. 12</u>	-	-	1	V
		V _D = 400 V; I _T = 100 mA; T _j = 125 °C; <u>Fig. 12</u>	0.15	-	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	2	μA
		V _D = 800 V; T _j = 125 °C	-	-	0.2	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic ch	aracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C};$ $I_{T(RMS)} = 0.8 \text{ A}; \text{ dV}_{com}/\text{dt} = 20 \text{ V/}\mu\text{s};$ (snubberless condition); gate open circuit; Fig. 14; Fig. 15	0.5	-	-	A/ms

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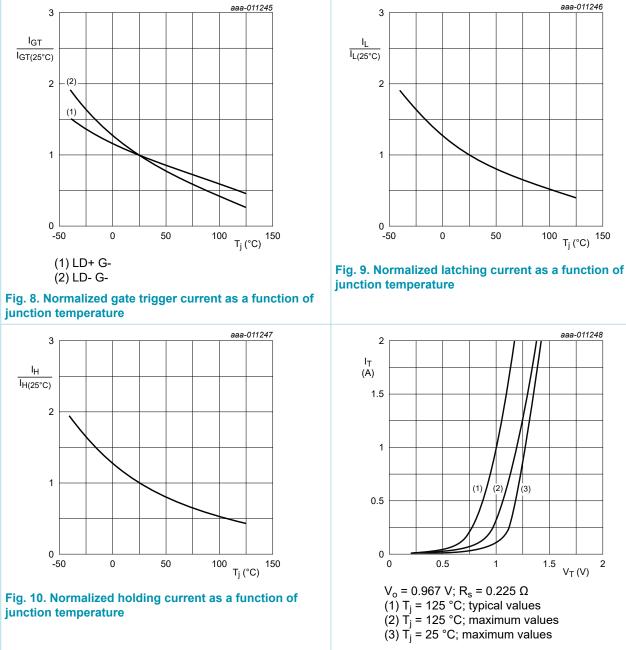
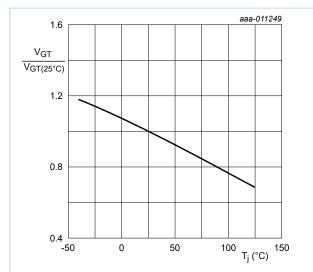


Fig. 11. On-state current as a function of on-state voltage

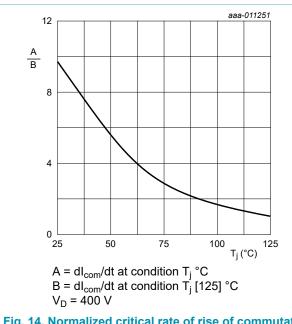
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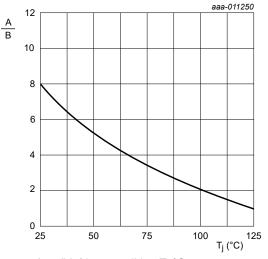
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A = dV_D/dt at condition T_j °C B = dV_D/dt at condition T_i [125] °C



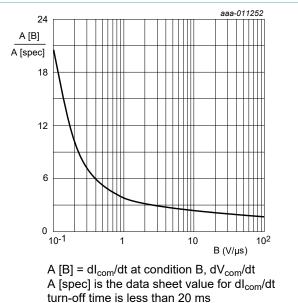
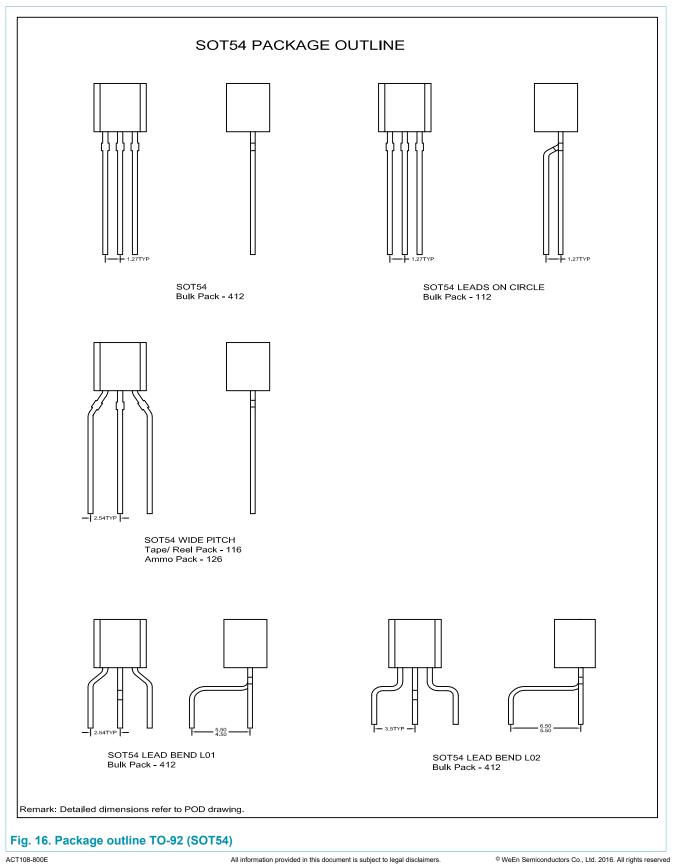


Fig. 15. Normalized critical rate of change of commutating current as a function of critical rate of change of commutating voltage; minimum values

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10. Package outline



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11. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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12. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Limiting values	3
8.	Thermal characteristics	6
9.	Characteristics	7
10	. Package outline	10
11.	. Legal information	11

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